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#### **Inclosure Material:**

Metal

**Overall Diameter:** 

0.300 inches

### **End Application:**

4920-01-054-8588 e/i fscm 81755

## Mounting Facility Quantity:

1

#### Mounting Method:

Press fit and threaded stud

#### **Features Provided:**

Hermetically sealed case

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 4.0 breakdown voltage, emitter-to-base, collector open

### **Current Rating Per Characteristic:**

10.00 milliamperes source cutoff current

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

voltage

#### **Test Data Document:**

12436-6010351 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Thread Series Designator:**

Unc

# Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0